SY88343BL

3.3V, 3.2 Gbps CML Limiting Post Amplifier with High Gain TTL Loss-of-Signal

Features

- · Single 3.3V Power Supply
- · DC to 3.2 Gbps Operation
- · Low-Noise CML Data Outputs
- · High Gain LOS
- Chatter-Free Open-Collector TTL Loss-of-Signal (LOS) Output with Internal 4.75 kΩ Pull-Up Resistor
- · TTL/EN Input
- Programmable LOS Level Set (LOS_{I VI})
- · Ideal for Multi-Rate Applications
- · Available in a 16-Lead VQFN Package

Applications

- · APON, BPON, EPON, and GPON
- · Gigabit Ethernet
- · Fibre Channel
- OC-3 and OC-12/24 SONET/SDH
- High-Gain Line Driver and Line Receiver

Markets

- FTTP
- · Optical Transceivers
- · Datacom/Telecom
- · Low-Gain TIA Interface
- · Long-Reach FOM

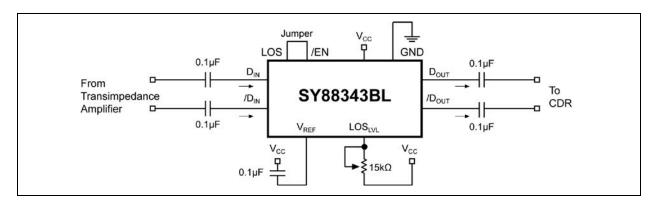
Typical Application Circuit

General Description

The SY88343BL low-power limiting post amplifier is designed for use in fiber-optic receivers. The device connects to typical transimpedance amplifiers (TIAs) that are AC-coupled. The linear signal output from TIAs can contain significant amounts of noise and may vary in amplitude over time. The SY88343BL quantizes these signals and outputs CML-level waveforms.

The SY88343BL operates from a single +3.3V power supply, over temperatures ranging from -40°C to +85°C. With its wide bandwidth and high gain, signals with data rates up to 3.2 Gbps and as small as 5 mV_{PP} can be amplified to drive devices with CML inputs or AC-coupled CML/PECL inputs.

The SY88343BL generates a high-gain loss-of-signal (LOS) open-collector TTL output. The LOS function has a high gain input stage for increased sensitivity. A programmable loss-of-signal level set pin (LOS $_{\rm LVL}$) sets the sensitivity of the input amplitude detection. LOS asserts high if the input amplitude falls below the threshold set by LOS $_{\rm LVL}$ and de-asserts low otherwise. The enable bar input (/EN) de-asserts the true output signal without removing the input signal. The LOS output can be fed back to the /EN input to maintain output stability under a loss-of-signal condition. Typically, 3.5 dB LOS hysteresis is provided to prevent chattering.



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Supply Voltage (V _{CC})	
input Voltage (DIN, /DIN)	
Output Current (I _{OUT})	
Continuous	±50 mA
Surge	±100 mA
/EN Voltage	0V to V _{CC}
V _{RFF} Current	
LOL _{LVL} Voltage	

Operating Ratings ‡

Supply Voltage (V_{CC})+3.0V to +3.6V

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

‡ Notice: The device is not guaranteed to function outside its operating ratings.

Note 1: Devices are ESD sensitive. Handling precautions recommended.

DC ELECTRICAL CHARACTERISTICS

Electrical Characteristics: V_{CC} = 3.0V to 3.6V; R_L = 50 Ω to V_{CC} ; T_A = -40°C to +85°C; typical values at V_{CC} = 3.3V, T_A = +25°C.

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Power Supply Current	I _{CC}	_	45	62	mA	No output load
LOS _{LVL} Voltage	V_{LOSLVL}	V_{REF}		V_{CC}	V	_
CML Output HIGH Voltage	V_{OH}	$V_{CC} - 0.020$	$V_{CC} - 0.005$	V_{CC}	>	_
CML Output LOW Voltage	V_{OL}	V _{CC} – 0.475	$V_{CC} - 0.4$	$V_{CC} - 0.350$	>	_
Differential Output Offset	V_{OFFSET}	_		±80	mV	_
Reference Voltage	V_{REF}	V _{CC} – 1.48	V _{CC} – 1.32	V _{CC} – 1.16	٧	_
Input Common Mode Range	V _{IHCMR}	GND + 2.0	_	V _{CC}	V	_
Single-Ended Output Impedance	Z _O	40	50	60	Ω	_
Single-Ended Input Impedance	Z _I	40	50	60	Ω	_

TTL DC ELECTRICAL CHARACTERISTICS

Electrical Characteristics: V_{CC} = 3.0V to 3.6V; T_A = -40°C to +85°C.

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
/EN Input HIGH Voltage	V _{IH}	2.0	_	_	V	_
/EN Input LOW Voltage	V_{IL}			0.8	V	_
/EN Input HICH Current		_	_	20	μA	V _{IN} = 2.7V
/EN Input HIGH Current	lН	_	_	100	μA	$V_{IN} = V_{CC}$
/EN Input LOW Current	I _{IL}	-0.3	_	_	mA	V _{IN} = 0.5V
LOS Output HIGH Level	\/	2.4	_	_	V	V _{CC} ≥ 3.3V, I _{OH-MAX} < 160 μA
LOS Output HIGH Level	V _{OH}	2.0	_	_	V	V _{CC} < 3.3V, I _{OH-MAX} < 160 μA
LOS Output LOW Level	V _{OL}	_	_	0.5	V	I _{OL} = +2 mA

AC ELECTRICAL CHARACTERISTICS

Electrical Characteristics: $V_{CC} = 3.0V$ to 3.6V; $T_A = -40$ °C to +85°C.

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Output Rise/Fall Time (20% to 80%)	t _r /t _f		60	120	ps	Note 1
Deterministic Jitter	4	_	15	_	ps _{PP}	Note 2
Random Jitter	t _{JITTER}		5		ps _{RMS}	Note 3
Differential Input Voltage Swing	V_{ID}	5	_	1800	mV_{PP}	Figure 4-2
Differential Output Voltage Swing	V _{OD}	700	800	950	mV_{PP}	V _{ID} ≥ 12 mV _{PP} , Figure 4-2
LOS Release Time	t _{OFF}		2	10	μs	
LOS Assert Time	t _{ON}		2	10	μs	_
Low LOS De-assert Level	LOS _{DL}	_	4.8	_	mV_{PP}	R_{LOSLVL} = 15 k Ω , Note 5
Low LOS Assert Level	LOS _{AL}		3.1		mV_{PP}	$R_{LOSLVL} = 15 \text{ k}\Omega, \text{ Note 5}$
Low LOS Hysteresis	HYS _L		3.8		dB	R_{LOSLVL} = 15 k Ω , Note 4
Medium LOS De-assert Level	LOS _{DM}	_	7.5	11	mV_{PP}	$R_{LOSLVL} = 5 k\Omega$, Note 5
Medium LOS Assert Level	LOS _{AM}	3	5.2		mV_{PP}	$R_{LOSLVL} = 5 k\Omega$, Note 5
LOS Hysteresis	HYS _M	2	3.2	4.5	dB	$R_{LOSLVL} = 5 k\Omega$, Note 4
High LOS De-assert Level	LOS _{DH}		18	23	mV_{PP}	$R_{LOSLVL} = 100\Omega$, Note 5
High LOS Assert Level	LOS _{AH}	8	12		mV_{PP}	$R_{LOSLVL} = 100\Omega$, Note 5
High LOS Hysteresis	HYS _H	2	3.5	4.5	dB	$R_{LOSLVL} = 100\Omega$, Note 4
3 dB Bandwidth	B _{-3dB}	_	2		GHz	_
Differential Voltage Gain	A _{V(DIFF)}	32	38	_	dB	_
Single-Ended Small-Signal Gain	S ₂₁	26	32	_	dB	_

- Note 1: Amplifier in limiting mode. Input is a 200 MHz square wave.
 - 2: Deterministic jitter measured using 3.2 Gbps K28.5 pattern, V_{ID} = 10 m V_{PP} .
 - 3: Random jitter measured using 3.2 Gbps K28.7 pattern, V_{ID} = 10 m V_{PP} .
 - **4:** This specification defines electrical hysteresis as 20log (LOS De-assert/LOS Assert). The ratio between optical hysteresis and electrical hysteresis is found to vary between 1.5 and 2, depending upon the level of received optical power and ROSA characteristics. Based upon that ratio, the optical hysteresis corresponding to the electrical hysteresis range 2 dB to 4.5 dB, shown in the AC characteristics table, will be 1 dB to 3 dB Optical Hysteresis.
 - **5:** See Figure 2-1 for a graph showing how to choose a particular R_{LOSLVL} for a particular LOS assert and its associated de-assert amplitude.

SY88343BL

TEMPERATURE SPECIFICATIONS (Note 1)

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions				
Temperature Ranges										
Ambient Temperature	T _A	-4 0	_	+85	°C	_				
Lead Temperature	_	_	_	+260	°C	Soldering, 10 sec.				
Storage Temperature	T _S	-65	_	+150	°C	_				
Package Thermal Resistance										
Thermal Resistance, VQFN 16-Ld,	θ_{JA}	_	61	_	°C/W	_				
Note 2	ΨЈВ	_	38	_	°C/W	_				

- Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A, T_J, θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +85°C rating. Sustained junction temperatures above +85°C can impact the device reliability.
 - 2: Thermal performance assumes the use of a 4-layer PCB. Exposed pad must be soldered (or equivalent) to the device's most negative potential on the PCB.

2.0 TYPICAL PERFORMANCE CURVES

Note:

The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

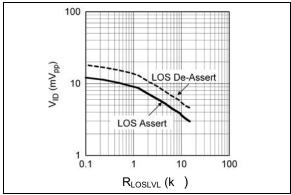


FIGURE 2-1: V_{ID} to Assert/De-Assert LOS vs. R_{LOSLVL} .

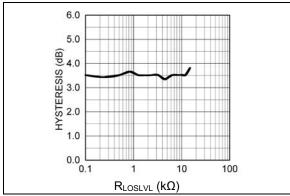
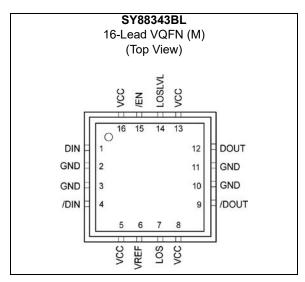


FIGURE 2-2: LOS Hysteresis vs. R_{LOSLVL}.

3.0 PIN DESCRIPTIONS

Package Type



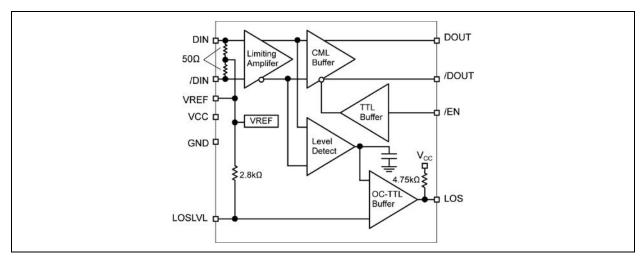
The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: PIN FUNCTION TABLE

Pin Number	Pin Name	Туре	Description
15	/EN	TTL Input: Default is high	/Enable: This input enables the outputs when it is LOW. Note that this input is internally connected to a 25 k Ω pull-up resistor and will default to logic HIGH state if left open.
1	DIN	Data Input	True data input.
4	/DIN	Data Input	Complementary data input.
6	VREF	_	Reference Voltage: Bypass with 0.01 µF low ESR capacitor from VREF to VCC to stabilize LOS _{LVL} and V _{REF} .
14	LOSLVL	Input	Loss-of-Signal Level Set: A resistor from this pin to V _{CC} sets the threshold for the data input amplitude at which the LOS output will be asserted.
2, 3, 10, 11	GND, Exposed Pad	Ground	Device ground. Exposed pad must be connected to PCB ground plane.
7	LOS	Open Collector TTL Output with internal 4.75 kΩ pull-down resistor	Loss-of-Signal: Asserts high when the data input amplitude falls below the threshold set by LOS _{LVL} .
9	/DOUT	CML Output	Complementary data output.
12	DOUT	CML Output	True data output.
5, 8, 13, 16	VCC	Power Supply	Positive power supply.

4.0 FUNCTIONAL DESCRIPTION

Functional Block Diagram



The SY88343BL low-power limiting post amplifier operates from a single +3.3V power supply, over temperatures from –40°C to +85°C. Signals with data rates up to 3.2 Gbps and as small as 5 mV $_{PP}$ can be amplified. Figure 4-1 shows the allowed input voltage swing. The SY88343BL generates a LOS output allowing feedback to /EN for output stability. LOS $_{LVL}$ sets the sensitivity of the input amplitude detection.

4.1 Input Amplifier Buffer

Figure 4-2 shows a simplified schematic of the input stage. The high-sensitivity of the input amplifier allows signals as small as $5\,\mathrm{mV_{PP}}$ to be detected and amplified. The input amplifier also allows input signals as large as $1800\,\mathrm{mV_{PP}}$. Input signals are linearly amplified with a typical $38\,\mathrm{dB}$ differential voltage gain. Because it is a limiting amplifier, this device outputs typically $800\,\mathrm{mV_{PP}}$ voltage-limited waveforms for input signals greater than $12\,\mathrm{mV_{PP}}$. Applications that require the SY88343BL to operate with high gain should have the upstream TIA placed as close as possible to the device's input pins. This ensures the best performance of the device.

4.2 Output Buffer

The SY88343BL's CML output buffer is designed to drive 50Ω lines. The output buffer requires appropriate termination for proper operation. An external 50Ω resistor to V_{CC} for each output pin provides this. Figure 4-4 shows a simplified schematic of the output stage.

4.3 Loss-of-Signal

The SY88343BL generates a chatter-free LOS open-collector TTL output with an internal 4.75 k Ω pull-up resistor, as shown in Figure 4-3. LOS is used to determine that the input amplitude is large enough to be considered a valid input. LOS asserts high if the input amplitude falls below the threshold sets by LOS_{LVL} and de-asserts low otherwise. LOS can be fed back to the enable bar (/EN) input to maintain output stability under a loss-of-signal condition. /EN de-asserts the true output signal without removing the input signals. Typical, 3.5 dB LOS hysteresis is provided to prevent chattering.

4.4 Loss-of-Signal Level Set

Programmable LOS level-set pin (LOS_{LVL}) sets the threshold of the input amplitude detection. Connecting an external resistor between V_{CC} and LOS_{LVL} sets the voltage at LOS_{LVL}. This voltage ranges from V_{CC} to V_{REF} . The external resistor creates a voltage divider between V_{CC} and V_{REF} , as shown in Figure 4-5.

4.5 Hysteresis

The SY88343BL provides typically 3.5 dB LOS electrical hysteresis. By definition, a power ratio measured in dB is 10log (power ratio). Power is calculated as $\rm V_{IN}{}^2/R$ for an electrical signal. Hence, the same ratio can be stated as 20log (voltage ratio). While in linear mode, the electrical voltage input changes linearly with the optical power and therefore, the ratios change linearly. Thus, the optical hysteresis in dB is half the electrical hysteresis in dB given in the data sheet. Because the SY88343BL is an electrical device, this data sheet refers to hysteresis in electrical terms. With 3.5 dB LOS hysteresis, a voltage factor of 1.5 is required to assert or de-assert LOS.

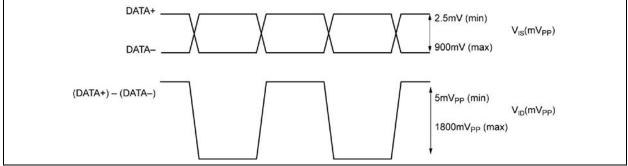


FIGURE 4-1: V_{IS} and V_{ID} .

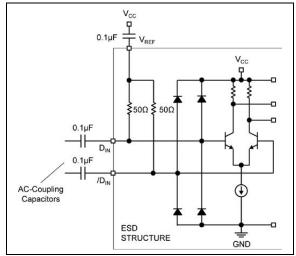


FIGURE 4-2: Input Structure.

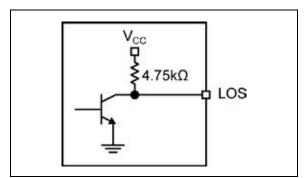


FIGURE 4-3: LOS Output Structure.

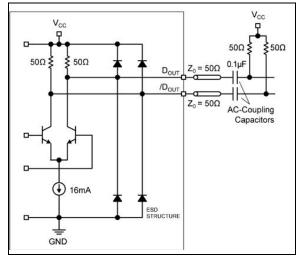


FIGURE 4-4: Output Structure.

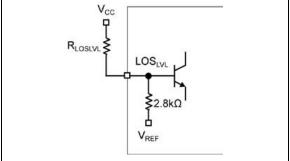
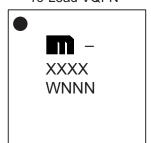


FIGURE 4-5: LOS_{LVL} Setting Circuit.

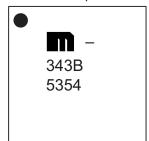
5.0 PACKAGING INFORMATION

5.1 Package Marking Information

16-Lead VQFN*



Example



Legend: XX...X Product code or customer-specific information

Y Year code (last digit of calendar year)
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

e3 Pb-free JEDEC® designator for Matte Tin (Sn)

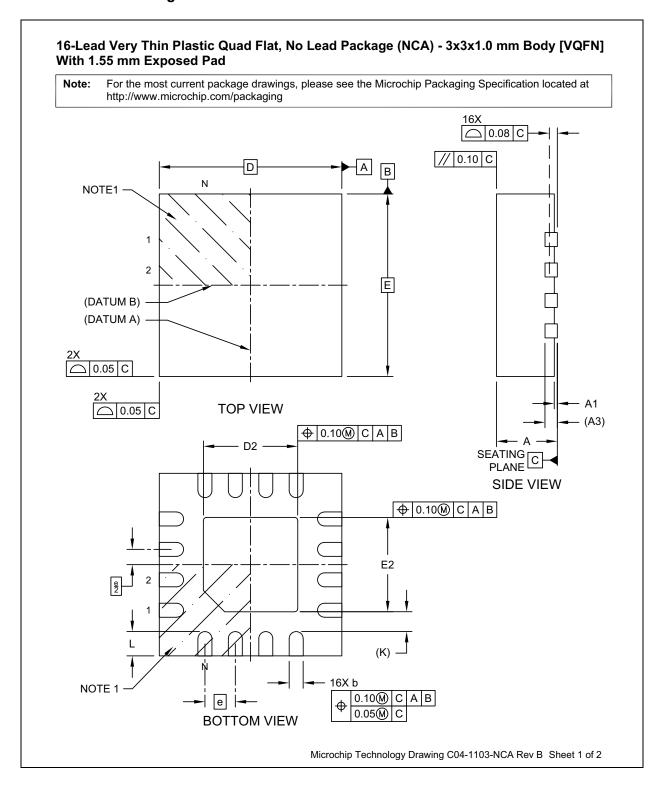
This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.

•, ▲, ▼ Pin one index is identified by a dot, delta up, or delta down (triangle mark).

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information. Package may or may not include the corporate logo.

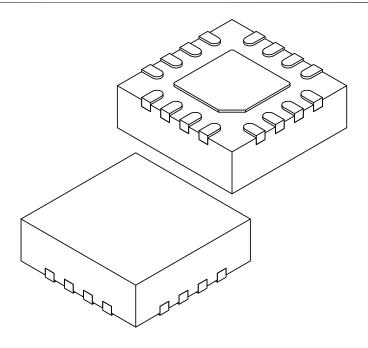
Underbar (_) and/or Overbar (_) symbol may not be to scale.

16-Lead VQFN Package Outline and Recommended Land Pattern



16-Lead Very Thin Plastic Quad Flat, No Lead Package (NCA) - 3x3x1.0 mm Body [VQFN] With 1.55 mm Exposed Pad

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX	
Number of Terminals	N		16		
Pitch	е		0.50 BSC		
Overall Height	Α	0.80	0.90	1.00	
Standoff	A1	0.00	0.02	0.05	
Terminal Thickness	A3	0.203 REF			
Overall Length	D	3.00 BSC			
Exposed Pad Length	D2	1.50	1.55	1.60	
Overall Width	Е	3.00 BSC			
Exposed Pad Width	E2	1.50	1.55	1.60	
Terminal Width	b	0.18	0.23	0.28	
Terminal Length	L	0.35	0.40	0.45	
Terminal-to-Exposed-Pad	K		0.33 REF		

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

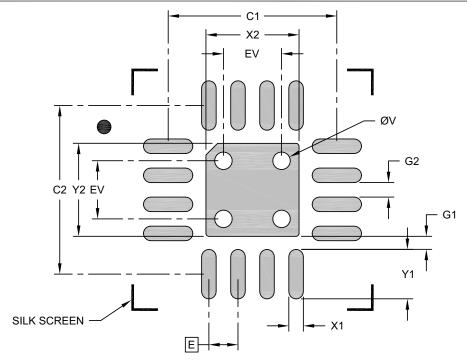
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1103-NCA Rev B $\,$ Sheet 2 of 2 $\,$

16-Lead Very Thin Plastic Quad Flat, No Lead Package (NCA) - 3x3x1.0 mm Body [VQFN] With 1.55 mm Exposed Pad

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX
Contact Pitch	Е		0.50 BSC	
Center Pad Width	X2			1.60
Center Pad Length	Y2			1.60
Contact Pad Spacing	C1		2.90	
Contact Pad Spacing	C2		2.90	
Contact Pad Width (Xnn)	X1			0.25
Contact Pad Length (Xnn)	Y1			0.85
Contact Pad to Center Pad (Xnn)	G1	0.23		
Contact Pad to Contact Pad (Xnn)	G2	0.25		
Thermal Via Diameter	V		0.30	
Thermal Via Pitch	EV		1.00	

Notes:

- 1. Dimensioning and tolerancing per ASME Y14.5M
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
- 2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

Microchip Technology Drawing C04-3103-NCA Rev B

APPENDIX A: REVISION HISTORY

Revision A (November 2021)

- Converted Micrel document SY88343BL to Microchip data sheet DS20006622A.
- Minor text changes throughout.

2	VS	R	3	43	R	
v		JU	J	TU	u	_

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

PART No.	<u>x</u>	<u>x</u>	<u>x</u>	- <u>XX</u>	Example	es:		
Device	Supply Voltage	Package	Temperature Range	Media Type	a) SY88	343BLMG:	SY88343B, 3.3V Supply Voltage, 16-Lead 3x3 VQFN, -40°C to +85°C Temp. Range	
Device:	SY88343E		CML Limiting Post <i>i</i> n TTL Loss-of-Signa		b) SY88	343BLMG-TR:	100/Tube SY88343B, 3.3V Supply Voltage, 16-Lead 3x3 VQFN,	
Supply Voltage:	L =	3.3V					-40°C to +85°C Temp. Range, 1,000/Reel	
Package:	M =	16-Lead 3 mm	x 3 mm VQFN		Note 1:		identifier only appears in the mber description. This identifier is	
Temperature Range:	G =	–40°C to +85°C	;			the device pac	ng purposes and is not printed on kage. Check with your Microchip r package availability with the option	
Media Type:	` ,	100/Tube 1,000/Reel				.aps and reor		

2	VS	R	3	43	R	
v		JU	J	TU	u	_

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